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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	I ² C, LINbus, SIO, SSU, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	59
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 5.5V
Data Converters	A/D 12x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LFQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21368cnfp-50

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

R8C/36C Group 1. Overview

Table 1.4 Product List for R8C/36C Group (2)

Current of Nov 2010

	ROM C	apacity	DAM			
Part No.	Program	Data flash	RAM Capacity	Package Type	Rer	marks
R5F21364CDFP	ROM 16 Kbytes	1 Khyto v 1	1.5 Khytos	PLQP0064KB-A	Dyorgion	
R5F21365CDFP	_	1 Kbyte x 4		PLQP0064KB-A	D VELSION	
R5F21366CDFP	32 Kbytes	-		PLQP0064KB-A		
		1 Kbyte x 4		PLQP0064KB-A		
R5F21367CDFP R5F21368CDFP	48 Kbytes 64 Kbytes	1 Kbyte x 4		PLQP0064KB-A		
R5F2136ACDFP	96 Kbytes	1 Kbyte x 4		PLQP0064KB-A		
R5F2136CCDFP	•	1 Kbyte x 4		PLQP0064KB-A		
R5F21364CDFA	16 Kbytes			PLQP0064GA-A		
R5F21365CDFA	_	1 Kbyte x 4		PLQP0064GA-A		
	24 Kbytes	-		PLQP0064GA-A		
R5F21366CDFA	32 Kbytes	•	•			
R5F21367CDFA	48 Kbytes	1 Kbyte × 4		PLQP0064GA-A		
R5F21368CDFA	64 Kbytes	1 Kbyte × 4		PLQP0064GA-A		
R5F2136ACDFA	96 Kbytes	1 Kbyte × 4	_	PLQP0064GA-A		
R5F2136CCDFA		1 Kbyte × 4	,	PLQP0064GA-A		
R5F21364CDFB (D)	16 Kbytes	1 Kbyte × 4	•	PTQP0064LB-A		
R5F21365CDFB (D)	24 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F21366CDFB (D)	32 Kbytes	1 Kbyte × 4	,	PTQP0064LB-A		
R5F21367CDFB (D)	48 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F21368CDFB (D)		1 Kbyte × 4		PTQP0064LB-A		
R5F2136ACDFB (D)	96 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F2136CCDFB (D)		1 Kbyte × 4	-	PTQP0064LB-A		
R5F21364CDXXXFP	16 Kbytes	•	•	PLQP0064KB-A	N version	Factory
R5F21365CDXXXFP	24 Kbytes	1 Kbyte × 4		PLQP0064KB-A		programming
R5F21366CDXXXFP	32 Kbytes	-		PLQP0064KB-A		product
R5F21367CDXXXFP	48 Kbytes	1 Kbyte × 4	4 Kbytes	PLQP0064KB-A		
R5F21368CDXXXFP	64 Kbytes	1 Kbyte × 4	6 Kbytes	PLQP0064KB-A		
R5F2136ACDXXXFP	96 Kbytes	1 Kbyte × 4		PLQP0064KB-A		
R5F2136CCDXXXFP	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064KB-A		
R5F21364CDXXXFA	16 Kbytes	1 Kbyte × 4	1.5 Kbytes	PLQP0064GA-A		
R5F21365CDXXXFA	24 Kbytes	1 Kbyte × 4	2 Kbytes	PLQP0064GA-A		
R5F21366CDXXXFA	32 Kbytes	1 Kbyte x 4	2.5 Kbytes	PLQP0064GA-A		
R5F21367CDXXXFA	48 Kbytes	1 Kbyte × 4	4 Kbytes	PLQP0064GA-A		
R5F21368CDXXXFA	64 Kbytes	1 Kbyte x 4	6 Kbytes	PLQP0064GA-A		
R5F2136ACDXXXFA	96 Kbytes	1 Kbyte × 4	8 Kbytes	PLQP0064GA-A		
R5F2136CCDXXXFA	128 Kbytes	1 Kbyte × 4	10 Kbytes	PLQP0064GA-A		
R5F21364CDXXXFB (D)	16 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F21365CDXXXFB (D)	24 Kbytes	1 Kbyte × 4	-	PTQP0064LB-A		
R5F21366CDXXXFB (D)	32 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F21367CDXXXFB (D)	48 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F21368CDXXXFB (D)	64 Kbytes	1 Kbyte × 4		PTQP0064LB-A		
R5F2136ACDXXXFB (D)	96 Kbytes	1 Kbyte × 4	,	PTQP0064LB-A		
R5F2136CCDXXXFB (D)	128 Kbytes	•	•	PTQP0064LB-A		

(D): Under development

Note:

1. The user ROM is programmed before shipment.

R8C/36C Group 1. Overview

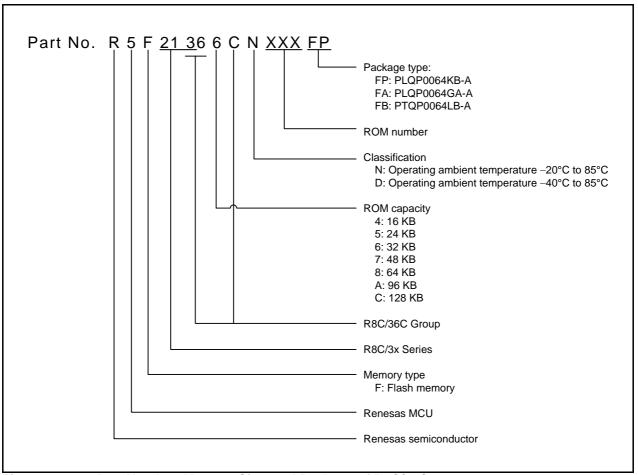


Figure 1.1 Part Number, Memory Size, and Package of R8C/36C Group

R8C/36C Group 1. Overview

1.3 Block Diagram

Figure 1.2 shows a Block Diagram.

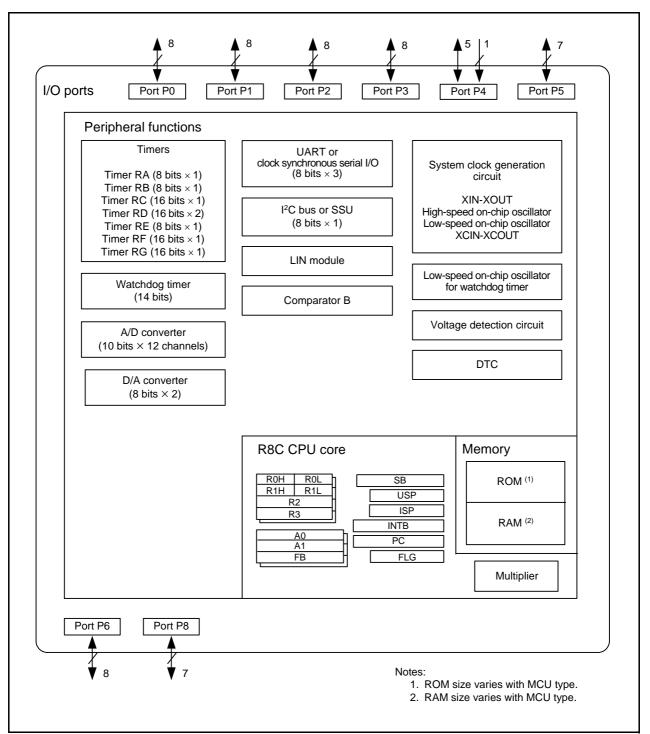


Figure 1.2 Block Diagram

2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.

Interrupts are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.

The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

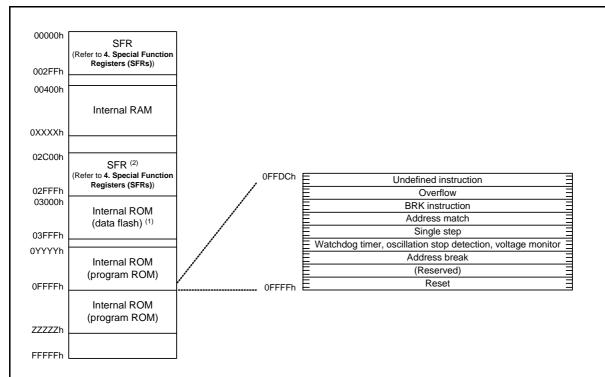
2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7. If a requested interrupt has higher priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

R8C/36C Group 3. Memory



- 1. The data flash indicates block A (1 Kbyte), block B (1 Kbyte), block C (1 Kbyte), and block D (1 Kbyte).
- 2. The SFR areas for the DTC and other modules are allocated to addresses 02C00h to 02FFFh.
- 3. The blank areas are reserved and cannot be accessed by users.

Part Number		Internal ROM	l	Internal RAM		
T dit (Valido)		Address 0YYYYh	Address ZZZZZh	Size	Address 0XXXXh	
R5F21364CNFP, R5F21364CDFP, R5F21364CNFA, R5F21364CDFA, R5F21364CDFB, R5F21364CNXXXFP, R5F21364CDXXXFP, R5F21364CDXXXFA, R5F21364CDXXXFA, R5F21364CNXXXFB, R5F21364CNXXXFB	16 Kbytes	0C000h	ı	1.5 Kbytes	009FFh	
R5F21365CNFP, R5F21365CDFP, R5F21365CNFA, R5F21365CDFA, R5F21365CNFB, R5F21365CDFB, R5F21365CNXXXFP, R5F21365CDXXXFP, R5F21365CNXXXFA, R5F21365CDXXXFA, R5F21365CNXXXFB, R5F21365CDXXXFB	24 Kbytes	0A000h	ı	2 Kbytes	00BFFh	
R5F21366CNFP, R5F21366CDFP, R5F21366CNFA, R5F21366CDFA, R5F21366CNFB, R5F21366CDFB, R5F21366CNXXXFP, R5F21366CDXXXFP, R5F21366CNXXXFA, R5F21366CDXXXFA, R5F21366CNXXXFB, R5F21366CDXXXFB	32 Kbytes	08000h	_	2.5 Kbytes	00DFFh	
R5F21367CNFP, R5F21367CDFP, R5F21367CNFA, R5F21367CDFA, R5F21367CNFB, RSF21367CDFB, R5F21367CNXXXFP, R5F21367CDXXXFP, R5F21367CDXXXFA, R5F21367CDXXXFA, R5F21367CDXXXFB, R5F21367CDXXXFB	48 Kbytes	04000h	-	4 Kbytes	013FFh	
R5F21368CNFP, R5F21368CDFP, R5F21368CNFA, R5F21368CDFA, R5F21368CNFB, R5F21368CDFB, R5F21368CNXXXFP, R5F21368CDXXXFP, R5F21368CNXXXFA, R5F21368CDXXXFA, R5F21368CNXXXFB, R5F21368CDXXXFB	64 Kbytes	04000h	13FFFh	6 Kbytes	01BFFh	
R5F2136ACNFP, R5F2136ACDFP, R5F2136ACNFA, R5F2136ACDFA, R5F2136ACNFB, R5F2136ACDFB, R5F2136ACNXXXFP, R5F2136ACDXXXFP, R5F2136ACNXXXFA, R5F2136ACDXXXFA, R5F2136ACNXXXFB, R5F2136ACDXXXFB	96 Kbytes	04000h	1BFFFh	8 Kbytes	023FFh	
R5F2136CCNFP, R5F2136CCDFP, R5F2136CCNFA, R5F2136CCDFA, R5F2136CCDFB, R5F2136CCDFB, R5F2136CCDXXXFP, R5F2136CCDXXXFP, R5F2136CCDXXXFA, R5F2136CCDXXXFA, R5F2136CCDXXXFB, R5F2136CCDXXXFB	128 Kbytes	04000h	23FFFh	10 Kbytes	02BFFh	

Figure 3.1 Memory Map of R8C/36C Group

4. Special Function Registers (SFRs)

An SFR (special function register) is a control register for a peripheral function. Tables 4.1 to 4.12 list the special function registers. Table 4.13 lists the ID Code Areas and Option Function Select Area.

Table 4.1 SFR Information (1) (1)

Address	Register	Symbol	After Reset
0000h	register	Symbol	Autor Reset
0001h			
0001h			
0002h			
0004h	Processor Mode Register 0	PM0	00h
0005h	Processor Mode Register 1	PM1	00h
0006h	System Clock Control Register 0	CMO	00101000b
0007h	System Clock Control Register 1	CM1	00100000b
0008h	Module Standby Control Register	MSTCR	00h
0009h	System Clock Control Register 3	CM3	00h
000Ah	Protect Register	PRCR	00h
000Bh	Reset Source Determination Register	RSTFR	0XXXXXXXb (2)
000Ch	Oscillation Stop Detection Register	OCD	00000100b
000Dh	Watchdog Timer Reset Register	WDTR	XXh
000Eh	Watchdog Timer Start Register	WDTS	XXh
000En	Watchdog Timer Control Register	WDTC	00111111b
0010h	valoridog Timor Control (Cegister	WETC	001111110
0011h			
0011h			
0012h			
0014h			
0015h	High-Speed On-Chip Oscillator Control Register 7	FRA7	When shipping
0015h	- 1.g.: Space on one domain control register /	1100	TTTOTT OTTIPPING
0017h			
0017h			
0019h			
001Ah			
0017th			
001Ch	Count Source Protection Mode Register	CSPR	00h
001011	Godin Godios Frotocilon Modo Rogistor	00111	10000000b (3)
001Dh			100000000 (-)
001Eh			
001En			
001FII			
0020h			
002111 0022h			
0022h	High-Speed On-Chip Oscillator Control Register 0	FRA0	00h
0023H	High-Speed On-Chip Oscillator Control Register 1	FRA1	When shipping
0024H	High-Speed On-Chip Oscillator Control Register 2	FRA2	00h
0025H	On-Chip Reference Voltage Control Register	OCVREFCR	00h
0020h	On-Chip Reference Voltage Control Register	OCVRETOR	0011
002711 0028h	Clock Prescaler Reset Flag	CPSRF	00h
0028h	High-Speed On-Chip Oscillator Control Register 4	FRA4	When shipping
0029h	High-Speed On-Chip Oscillator Control Register 4 High-Speed On-Chip Oscillator Control Register 5	FRA5	When shipping
002An	High-Speed On-Chip Oscillator Control Register 6	FRA6	When shipping
002BH	Trigit Speed Off-Offip Osolilator Contitor Negister 0	TRAU	witeri stiippilig
002Ch			
002Dh			
002En	High-Speed On-Chip Oscillator Control Register 3	FRA3	When shipping
			- ''
0030h 0031h	Voltage Monitor Circuit Control Register Voltage Monitor Circuit Edge Select Register	CMPA VCAC	00h 00h
003111 0032h	VOILAGE MOTHER CHICAL LAGE DETECT INEGISTED	VOAC	0011
0032h	Voltage Detect Register 1	VCA1	00001000b
0033h	Voltage Detect Register 1 Voltage Detect Register 2	VCA1	0000 1000b
003411	Vollage Deleti Negislei 2	VOAZ	
225-			00100000b ⁽⁵⁾
0035h		.= =	
0036h	Voltage Detection 1 Level Select Register	VD1LS	00000111b
0037h		<u>.</u>	
0038h	Voltage Monitor 0 Circuit Control Register	VW0C	1100X010b (4)
			1100X011b (5)
		VW1C	10001010b

X: Undefined

- 1. The blank areas are reserved and cannot be accessed by users.
- 2. The CWR bit in the RSTFR register is set to 0 after power-on and voltage monitor 0 reset. Hardware reset, software reset, or watchdog timer reset does not affect this bit.
- 3. The CSPROINI bit in the OFS register is set to 0.
- 4. The LVDAS bit in the OFS register is set to 1.
- 5. The LVDAS bit in the OFS register is set to 0.



SFR Information (2) (1) Table 4.2

Address	Register	Symbol	After Reset
003Ah	Voltage Monitor 2 Circuit Control Register	VW2C	10000010b
003Bh			
003Ch			
003Dh			
003Eh			
003Fh			
0040h			
0040H	Floor Momony Doody Interview Control Docietor	FMRDYIC	XXXXX000b
	Flash Memory Ready Interrupt Control Register	FINIRDTIC	AAAAAUUUD
0042h			
0043h			
0044h			
0045h			
0046h	INT4 Interrupt Control Register	INT4IC	XX00X000b
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h	Timer RD0 Interrupt Control Register	TRD0IC	XXXXX000b
0049h	Timer RD1 Interrupt Control Register	TRD1IC	XXXXX000b
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh	UART2 Transmit Interrupt Control Register	S2TIC	XXXXX000b
004Ch	UART2 Receive Interrupt Control Register	S2RIC	XXXXX000b
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Bh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b XXXXX000b
		_	
004Fh	SSU Interrupt Control Register/IIC bus Interrupt Control Register (2)	SSUIC/IICIC	XXXXX000b
0050h	Timer RF Compare 1 Interrupt Control Register	CMP1IC	XXXXX000b
0051h	UART0 Transmit Interrupt Control Register	SOTIC	XXXXX000b
0052h	UARTO Receive Interrupt Control Register	SORIC	XXXXX000b
0053h	UART1 Transmit Interrupt Control Register	S1TIC	XXXXX000b
0054h	UART1 Receive Interrupt Control Register	S1RIC	XXXXX000b
0055h	INT2 Interrupt Control Register	INT2IC	XX00X000b
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h	Timor to timorapt control regiotor	110.10	70000000
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh	Timer RF Interrupt Control Register	TRFIC	XXXXX000b
005Ch	Timer RF Compare 0 Interrupt Control Register	CMP0IC	XXXXX000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh	UART2 Bus Collision Detection Interrupt Control Register	U2BCNIC	XXXXX000b
005Fh	Timer RF Capture Interrupt Control Register	CAPIC	XXXXX000b
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh	Timer RG Interrupt Control Register	TRGIC	XXXXX000b
006Ch			
006Dh			
006Eh			
006Fh			
000111 0070h			
0070H			
	Voltage Maniter 1 Interrupt Central Register	VCMD4IC	VVVVV
0072h	Voltage Monitor 1 Interrupt Control Register	VCMP1IC	XXXXX000b
0073h	Voltage Monitor 2 Interrupt Control Register	VCMP2IC	XXXXX000b
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
0073h			
007An			
007Ch			
007Dh			
007Eh			
007Fh	<u> </u>		1

- The blank areas are reserved and cannot be accessed by users.
 Selectable by the IICSEL bit in the SSUIICSR register.

SFR Information (4) (1) Table 4.4

Address	Register	Symbol	After Reset
	A/D Register 0	AD0	XXh
00C1h			000000XXb
00C2h	A/D Register 1	AD1	XXh
00C3h			000000XXb
00C4h	A/D Register 2	AD2	XXh
00C5h	ū		000000XXb
	A/D Register 3	AD3	XXh
00C7h	7 12 1 (og)(sto) 0	1.20	000000XXb
	A/D Register 4	AD4	XXh
00C9h	77D Register 4	7.54	000000XXb
	A/D Register 5	AD5	XXh
00CBh	A/D (register 5	AD3	000000XXb
	A/D Register 6	AD6	XXh
00CDh	A/D Register 0	ADO	000000XXb
	A/D Register 7	AD7	XXh
	A/D Register /	AD7	
00CFh			000000XXb
00D0h			
00D1h			
00D2h			
00D3h			
	A/D Mode Register	ADMOD	00h
	A/D Input Select Register	ADINSEL	11000000b
00D6h	A/D Control Register 0	ADCON0	00h
	A/D Control Register 1	ADCON1	00h
00D8h	D/A0 Register	DA0	00h
	D/A1 Register	DA1	00h
00DAh			
00DBh			
	D/A Control Register	DACON	00h
00DDh	Ü		
00DEh			
00DFh			
	Port P0 Register	P0	XXh
	Port P1 Register	P1	XXh
00E2h	Port P0 Direction Register	PD0	00h
00E3h	Port P1 Direction Register	PD1	00h
	Port P2 Register	P2	XXh
	Port P3 Register	P3	XXh
00E6h	Port P2 Direction Register	PD2	00h
	Port P3 Direction Register	PD3	00h
		P4	
	Port P4 Register		XXh
	Port P5 Register	P5	XXh
00EAh	Port P4 Direction Register	PD4	00h
	Port P5 Direction Register	PD5	00h
	Port P6 Register	P6	XXh
00EDh			
00EEh	Port P6 Direction Register	PD6	00h
00EFh			
	Port P8 Register	P8	XXh
00F1h			
00F2h	Port P8 Direction Register	PD8	00h
00F3h			
00F4h			
00F5h			
00F6h			
00F7h			
00F8h			
00F9h			
00FAh			1
00FBh			1
00FCh			
00FDh			
00FEh 00FFh			
			1

Note:

1. The blank areas are reserved and cannot be accessed by users.

Table 4.7 SFR Information (7) (1)

Address	Register	Symbol	After Reset
0180h	Timer RA Pin Select Register	TRASR	00h
0181h	Timer RB/RC Pin Select Register	TRBRCSR	00h
0182h	Timer RC Pin Select Register 0	TRCPSR0	00h
0183h	Timer RC Pin Select Register 1	TRCPSR1	00h
0184h	Timer RD Pin Select Register 0	TRDPSR0	00h
0185h	Timer RD Pin Select Register 1	TRDPSR1	00h
0186h	Timer Pin Select Register	TIMSR	00h
0187h	Timer RF Output Control Register	TRFOUT	00h
0188h	UART0 Pin Select Register	U0SR	00h
0189h	UART1 Pin Select Register	U1SR	00h
018Ah	UART2 Pin Select Register 0	U2SR0	00h
018Bh	UART2 Pin Select Register 1	U2SR1	00h
018Ch	SSU/IIC Pin Select Register	SSUIICSR	00h
018Dh			
018Eh	INT Interrupt Input Pin Select Register	INTSR	00h
018Fh	I/O Function Pin Select Register	PINSR	00h
0190h	·		
0191h			
0192h			
0193h	SS Bit Counter Register	SSBR	11111000b
0194h	SS Transmit Data Register L / IIC bus Transmit Data Register (2)	SSTDR / ICDRT	FFh
0195h	SS Transmit Data Register H (2)	SSTDRH	FFh
0195h	SS Receive Data Register L / IIC bus Receive Data Register (2)	SSRDR / ICDRR	FFh
0197h	SS Receive Data Register H (2)	SSRDRH	FFh
0198h	SS Control Register H / IIC bus Control Register 1 (2)	SSCRH / ICCR1	00h
0199h	SS Control Register L / IIC bus Control Register 2 (2)	SSCRL / ICCR2	01111101b
019Ah	SS Mode Register / IIC bus Mode Register (2)	SSMR / ICMR	00010000b / 00011000b
019Bh	SS Enable Register / IIC bus Interrupt Enable Register (2)	SSER / ICIER	00h
019Ch	SS Status Register / IIC bus Status Register (2)	SSSR / ICSR	00h / 0000X000b
019Dh	SS Mode Register 2 / Slave Address Register (2)	SSMR2 / SAR	00h
019Eh	33 Mode Register 27 Stave Address Register (-)	CONTRET OF IR	0011
019Fh			
01A0h			
01A1h			
01A2h			
01A3h			
01A4h			
01A5h			
01A6h			
01A7h			
01A8h			
01A9h			
01AAh			
01ABh			
01ACh			
01ADh			
01AEh			
01AFh			
01B0h			
01B1h			
01B2h	Flash Memory Status Register	FST	10000X00b
01B3h			
01B4h	Flash Memory Control Register 0	FMR0	00h
01B5h	Flash Memory Control Register 1	FMR1	00h
01B6h	Flash Memory Control Register 2	FMR2	00h
01B7h	, ,		
01B8h			
01B9h			
01BAh			+
01BBh			+
01BCh			
01BDh			
01BEh			
01BEh			+
		ı	1

^{1.} The blank areas are reserved and cannot be accessed by users.

^{2.} Selectable by the IICSEL bit in the SSUIICSR register.

Table 4.11 SFR Information (11) (1)

Address	Register	Symbol	After Reset
	TC Control Data 14	DTCD14	XXh
2CB1h			XXh
2CB2h			XXh
2CB3h			XXh
2CB4h			XXh
2CB5h			XXh
2CB6h			XXh
2CB7h			XXh
	TC Control Data 15	DTCD15	XXh
2CB9h	TO CONTROL Data 15	D16B13	XXh
2CBAh			XXh
2CBBh			XXh
2CBCh			XXh
2CBDh			
			XXh
2CBEh			XXh
2CBFh			XXh
	TC Control Data 16	DTCD16	XXh
2CC1h			XXh
2CC2h			XXh
2CC3h			XXh
2CC4h			XXh
2CC5h			XXh
2CC6h			XXh
2CC7h			XXh
	TC Control Data 17	DTCD17	XXh
2CC9h			XXh
2CCAh			XXh
2CCBh			XXh
2CCCh			XXh
2CCDh			XXh
2CCEh			XXh
2CCFh			XXh
	TC Control Data 18	DTCD18	XXh
2CD1h	TO CONTROL Data To	DICDIO	XXh
2CD2h			XXh
2CD2h			XXh
2CD4h			XXh
2CD5h			XXh
2CD6h			XXh
2CD7h	TO 0 I.D	DT00.40	XXh
	TC Control Data 19	DTCD19	XXh
2CD9h			XXh
2CDAh			XXh
2CDBh			XXh
2CDCh			XXh
2CDDh			XXh
2CDEh			XXh
2CDFh			XXh
2CE0h D	TC Control Data 20	DTCD20	XXh
2CE1h			XXh
2CE2h			XXh
2CE3h			XXh
2CE4h			XXh
2CE5h			XXh
2CE6h			XXh
2CE7h			XXh
	TC Control Data 21	DTCD21	XXh
2CE9h	. 5 555. Data 21	D10021	XXh
2CEAh			XXh
2CEBh			
			XXh
2CECh			XXh
2CEDh			XXh
2CEEh			XXh
2CEFh			XXh

Note

1. The blank areas are reserved and cannot be accessed by users.

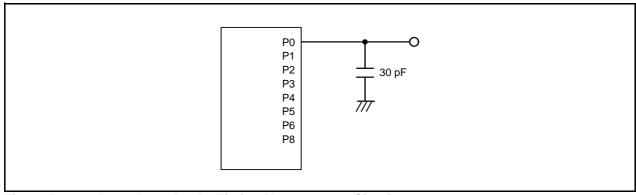


Figure 5.1 Ports P0 to P6, P8 Timing Measurement Circuit

Table 5.3 A/D Converter Characteristics

Symbol	Parameter		Cone	ditions		Standard	l	Unit
Symbol	Farameter	r arameter Conditions		Min.	Тур.	Max.	Offic	
_	Resolution		Vref = AVCC		_	_	10	Bit
_	Absolute accuracy	10-bit mode	Vref = AVCC = 5.0 V	AN0 to AN7 input, AN8 to AN11 input		_	±3	LSB
			Vref = AVCC = 3.3 V	AN0 to AN7 input, AN8 to AN11 input	l	_	±5	LSB
			Vref = AVCC = 3.0 V	AN0 to AN7 input, AN8 to AN11 input		_	±5	LSB
			Vref = AVCC = 2.2 V	AN0 to AN7 input, AN8 to AN11 input		_	±5	LSB
		8-bit mode	Vref = AVCC = 5.0 V	AN0 to AN7 input, AN8 to AN11 input		_	±2	LSB
			Vref = AVCC = 3.3 V	AN0 to AN7 input, AN8 to AN11 input		_	±2	LSB
			Vref = AVCC = 3.0 V	AN0 to AN7 input, AN8 to AN11 input	1	_	±2	LSB
			Vref = AVCC = 2.2 V	AN0 to AN7 input, AN8 to AN11 input		_	±2	LSB
φAD	A/D conversion clock	•	$4.0 \text{ V} \leq \text{Vref} = \text{AVcc} \leq 5.5 \text{ V} (2)$		2	_	20	MHz
			3.2 V ≤ Vref = AVcc ≤ 5.5 V (2)		2	_	16	MHz
			2.7 V ≤ Vref = AVcc ≤ 5.5 V (2)		2	_	10	MHz
			2.2 V ≤ Vref = AVCC ≤	≤ 5.5 V ⁽²⁾	2	_	5	MHz
_	Tolerance level impedance	е				3	_	kΩ
tconv	Conversion time	10-bit mode	Vref = AVCC = 5.0 V,	φAD = 20 MHz	2.2	_	_	μS
		8-bit mode	Vref = AVCC = 5.0 V,	φAD = 20 MHz	2.2	_	_	μS
tsamp	Sampling time		φAD = 20 MHz		8.0	_	_	μS
lVref	Vref current		Vcc = 5.0 V, XIN = f1 = φAD = 20 MHz		_	45	_	μА
Vref	Reference voltage				2.2	_	AVcc	V
VIA	Analog input voltage (3)				0	_	Vref	V
OCVREF	On-chip reference voltage		$2 \text{ MHz} \le \phi \text{AD} \le 4 \text{ MHz}$	Hz	1.19	1.34	1.49	V

^{1.} $Vcc/AVcc = V_{ref} = 2.2$ to 5.5 V, Vss = 0 V, and $T_{opr} = -20$ to 85 °C (N version)/-40 to 85 °C (D version), unless otherwise specified.

^{2.} The A/D conversion result will be undefined in wait mode, stop mode, when the flash memory stops, and in low-current-consumption mode. Do not perform A/D conversion in these states or transition to these states during A/D conversion.

^{3.} When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

Table 5.8 Voltage Detection 0 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Unit		
Symbol	Farameter	Condition	Min.	Тур.	Max.	Offic
Vdet0	Voltage detection level Vdet0_0 (2)		1.80	1.90	2.05	V
	Voltage detection level Vdet0_1 (2)		2.15	2.35	2.50	V
	Voltage detection level Vdet0_2 (2)		2.70	2.85	3.05	V
	Voltage detection level Vdet0_3 (2)		3.55	3.80	4.05	V
_	Voltage detection 0 circuit response time (4)	At the falling of Vcc from 5.0 V to (Vdet0_0 - 0.1) V	_	6	150	μS
_	Voltage detection circuit self power consumption	VCA25 = 1, Vcc = 5.0 V	_	1.5		μΑ
td(E-A)	Waiting time until voltage detection circuit operation starts (3)		_	_	100	μ\$

Notes:

- 1. The measurement condition is Vcc = 1.8 to 5.5 V and Topr = -20 to 85 °C (N version)/-40 to 85 °C (D version).
- 2. Select the voltage detection level with bits VDSEL0 and VDSEL1 in the OFS register.
- 3. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA25 bit in the VCA2 register to 0.
- 4. Time until the voltage monitor 0 reset is generated after the voltage passes Vdeto.

Table 5.9 Voltage Detection 1 Circuit Electrical Characteristics

Symbol	Parameter	Condition		Standard		Unit
Symbol	Parameter	Condition	Min.	Тур.		
Vdet1	Voltage detection level Vdet1_0 (2)	At the falling of Vcc	2.00	2.20	2.40	V
	Voltage detection level Vdet1_1 (2)	At the falling of Vcc	2.15	2.35	2.55	V
	Voltage detection level Vdet1_2 (2)	At the falling of Vcc	2.30	2.50	2.70	V
	Voltage detection level Vdet1_3 (2)	At the falling of Vcc	2.45	2.65	2.85	V
	Voltage detection level Vdet1_4 (2)	At the falling of Vcc	2.60	2.80	3.00	V
	Voltage detection level Vdet1_5 (2)	At the falling of Vcc	2.75	2.95	3.15	V
	Voltage detection level Vdet1_6 (2)	At the falling of Vcc	2.85	3.10	3.40	V
	Voltage detection level Vdet1_7 (2)	At the falling of Vcc	3.00	3.25	3.55	V
	Voltage detection level Vdet1_8 (2)	At the falling of Vcc	3.15	3.40	3.70	V
	Voltage detection level Vdet1_9 (2)	At the falling of Vcc	3.30	3.55	3.85	V
	Voltage detection level Vdet1_A (2)	At the falling of Vcc	3.45	3.70	4.00	V
	Voltage detection level Vdet1_B (2)	At the falling of Vcc	3.60	3.85	4.15	V
	Voltage detection level Vdet1_C (2)	At the falling of Vcc	3.75	4.00	4.30	V
	Voltage detection level Vdet1_D (2)	At the falling of Vcc	3.90	4.15	4.45	V
	Voltage detection level Vdet1_E (2)	At the falling of Vcc	4.05	4.30	4.60	V
	Voltage detection level Vdet1_F (2)	At the falling of Vcc	V			
_	Hysteresis width at the rising of Vcc in voltage detection 1 circuit		_	0.07	_	V
				0.10	_	V
_	Voltage detection 1 circuit response time (3)		_	60	150	μS
_	Voltage detection circuit self power consumption	VCA26 = 1, Vcc = 5.0 V	_	1.7	_	μА
td(E-A)	Waiting time until voltage detection circuit operation starts ⁽⁴⁾		_	_	100	μS

- 1. The measurement condition is Vcc = 1.8 to 5.5 V and T_{opr} = -20 to 85 °C (N version)/-40 to 85 °C (D version).
- 2. Select the voltage detection level with bits VD1S0 to VD1S3 in the VD1LS register.
- 3. Time until the voltage monitor 1 interrupt request is generated after the voltage passes Vdet1.
- 4. Necessary time until the voltage detection circuit operates when setting to 1 again after setting the VCA26 bit in the VCA2 register to 0.

Table 5.18 Electrical Characteristics (2) [3.3 V \leq Vcc \leq 5.5 V] (Topr = -20 to 85 °C (N version)/-40 to 85 °C (D version), unless otherwise specified.)

Const. :	Danasatas	O a selffer a			Standard			
Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit	
CC	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode,	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	6.5	15	mA	
output pins are open, other pins are Vss		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	5.3	12.5	mA		
		XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	_	3.6	_	mA		
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	3.0	_	mA	
		XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	2.2	_	mA		
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.5	_	mA	
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	7.0	15	mA	
			XIN clock off High-speed on-chip oscillator on fOCO-F = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	3.0	_	mA	
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16, MSTIIC = MSTTRD = MSTTRC = 1	_	1	_	mA	
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	_	90	400	μА	
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	_	85	400	μА	
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM	_	47	_	μА	
			Flash memory off, FMSTP = 1, VCA20 = 0					
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	_	15	100	μА	
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	_	4	90	μА	
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	_	3.5	_	μА	
		Stop mode	XIN clock off, Topr = 25 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off	_	2.0	5.0	μА	
			VCÁ27 = VCA26 = VCA25 = 0			<u> </u>		
			XIN clock off, Topr = 85 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off	_	15	_	μА	

Table 5.22 Serial Interface

Symbol	Parameter	Standard Min. Max.		Unit
	raidilletei			Offic
tc(CK)	CLKi input cycle time	200	_	ns
tw(ckh)	CLKi input "H" width	100	_	ns
tW(CKL)	CLKi input "L" width	100	_	ns
td(C-Q)	TXDi output delay time	_	50	ns
th(C-Q)	TXDi hold time	0	_	ns
tsu(D-C)	RXDi input setup time	50	_	ns
th(C-D)	RXDi input hold time	90	_	ns

i = 0 to 2

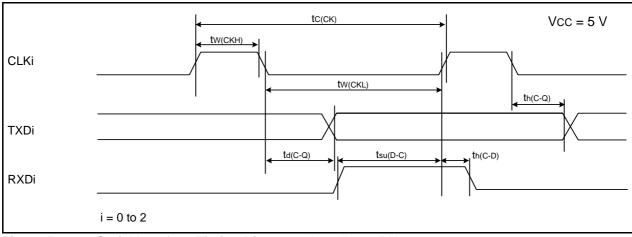


Figure 5.11 Serial Interface Timing Diagram when Vcc = 5 V

Table 5.23 External Interrupt INTi (i = 0 to 4) Input, Key Input Interrupt Kli (i = 0 to 3)

Symbol	Parameter	Stan	dard	Unit
Symbol	raidilielei	Min. Max. 250 (1) —	Offic	
tw(INH)	INTi input "H" width, Kli input "H" width	250 (1)	_	ns
tW(INL)	INTi input "L" width, Kli input "L" width	250 ⁽²⁾	_	ns

- 1. When selecting the digital filter by the INTi input filter select bit, use an INTi input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- 2. When selecting the digital filter by the INTi input filter select bit, use an INTi input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

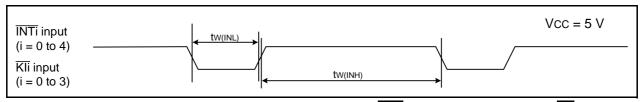


Figure 5.12 Input Timing Diagram for External Interrupt INTi and Key Input Interrupt Kli when Vcc = 5 V

Table 5.31 Electrical Characteristics (5) [1.8 V \leq VCC < 2.7 V]

Symbol	Dox	ameter	Conditi	0.0	S	Standard		Unit
Symbol	i alametei		Condition		Min.	Тур.	Max.	Unit
Vон	Output "H" voltage	Other than XOUT	Drive capacity High	Iон = −2 mA	Vcc - 0.5	_	Vcc	V
			Drive capacity Low	IOH = −1 mA	Vcc - 0.5		Vcc	V
		XOUT		IoH = -200 μA	1.0	_	Vcc	V
Vol	Output "L" voltage	Other than XOUT	Drive capacity High	IoL = 2 mA	_		0.5	V
			Drive capacity Low	IoL = 1 mA	_	_	0.5	V
		XOUT		IoL = 200 μA	_	_	0.5	V
VT+-VT-	Hysteresis	NTO, INT1, INT2, INT3, INT4, KIO, KI1, KI2, KI3, TRAIO, TRBO, TRCIOA, TRCIOB, TRCIOC, TRDIOAO, TRDIOAO, TRDIOAO, TRDIOAO, TRDIOAO, TRDIOAI, TRDIOCI, TRDIOCI, TRDIOCI, TRCICA, TRGIOA, TRGIOA, TRGIOA, TRGIOA, TRGIOA, RXD0, RXD1, RXD2, CLK0, CLK1, CLK2, SSI, SCL, SDA, SSO RESET			0.05	0.20	_	V
Iн	Input "H" current		$V_1 = 2.2 \text{ V}, \text{ Vcc} = 2.2 \text{ V}$	2 V	_	_	4.0	μА
lıL	Input "L" current		VI = 0 V, Vcc = 2.2 V	V	_	_	-4.0	μА
RPULLUP	Pull-up resistance		VI = 0 V, Vcc = 2.2 V	V	70	140	300	kΩ
RfXIN	Feedback resistance	XIN			_	0.3	_	МΩ
RfXCIN	Feedback resistance	XCIN			_	8	_	MΩ
VRAM	RAM hold voltage		During stop mode		1.8		_	V

^{1.} $1.8 \text{ V} \leq \text{Vcc} < 2.7 \text{ V}$, $\text{Topr} = -20 \text{ to } 85 ^{\circ}\text{C}$ (N version)/ $-40 \text{ to } 85 ^{\circ}\text{C}$ (D version), and f(XIN) = 5 MHz, unless otherwise specified.

Table 5.32 Electrical Characteristics (6) [1.8 V \leq Vcc < 2.7 V] (Topr = -20 to 85 °C (N version)/-40 to 85 °C (D version), unless otherwise specified.)

Symbol	Power supply current (Vcc = 1.8 to 2.7 V) Single-chip mode, output pins are open. High-speed clock mode XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	Parameter Condition	,	Standar	d	Unit	
			Min.	Тур.	Max.	Unit	
		_	2.2	_	mA		
	other pins are Vss		XIN = 5 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	0.8	_	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz No division	_	2.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 5 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	_	1.7	_	mA
			XIN clock off High-speed on-chip oscillator on fOCO-F = 4 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-16, MSTIIC = MSTTRD = MSTTRC = 1	_	1	_	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR27 = 1, VCA20 = 0	_	90	300	μА
		Low-speed clock mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division FMR27 = 1, VCA20 = 0	_	80	350	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz No division Program operation on RAM Flash memory off, FMSTP = 1, VCA20 = 0	_	40	_	μА
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	_	15	90	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = VCA25 = 0, VCA20 = 1	_	4	80	μА
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz (peripheral clock off) While a WAIT instruction is executed VCA27 = VCA26 = VCA25 = 0, VCA20 = 1		3.5	_	μА
		Stop mode	XIN clock off, Topr = 25 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA25 = VCA26 = VCA25 = 0	_	2.0	5	μА
			VCA27 = VCA26 = VCA25 = 0 XIN clock off, Topr = 85 °C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off	_	15	_	μА

Timing requirements (Unless Otherwise Specified: Vcc = 2.2 V, Vss = 0 V, Topr = 25 °C)

Table 5.33 External Clock Input (XOUT, XCIN)

Symbol	Parameter	Stan	dard	Unit
	Falanielei	Min. Max.		Offic
tc(XOUT)	XOUT input cycle time	200	_	ns
twh(xout)	XOUT input "H" width	90	_	ns
twl(xout)	XOUT input "L" width 90 —			
tc(XCIN)	XCIN input cycle time 14 —			
twh(xcin)	XCIN input "H" width	7	_	μS
tWL(XCIN)	XCIN input "L" width 7 —			

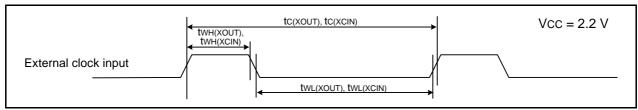


Figure 5.18 External Clock Input Timing Diagram when VCC = 2.2 V

Table 5.34 TRAIO Input

Symbol	Parameter	Stand	dard	Unit
	raidilletei	Min.	Max.	Offit
tc(TRAIO)	TRAIO input cycle time	500	_	ns
twh(traio)	TRAIO input "H" width	200	_	ns
tWL(TRAIO)	TRAIO input "L" width	200	_	ns

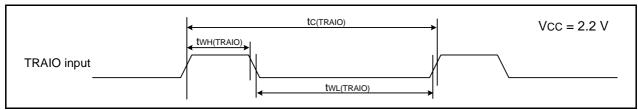


Figure 5.19 TRAIO Input Timing Diagram when Vcc = 2.2 V

Table 5.35 TRFI Input

Symbol	Parameter	Standard		Unit
	raianielei	Min. Max.	Offic	
tc(TRFI)	TRFI input cycle time	2000 (1)	_	ns
twh(TRFI)	TRFI input "H" width 1000 (2) —			
tWL(TRFI)	TRFI input "L" width	1000 (2)	_	ns

- 1. When using timer RF input capture mode, adjust the cycle time to (1/timer RF count source frequency × 3) or above.
- 2. When using timer RF input capture mode, adjust the pulse width to (1/timer RF count source frequency × 1.5) or above.

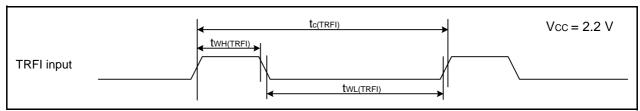


Figure 5.20 TRFI Input Timing Diagram when Vcc = 2.2 V

Rev.	Date		Description
Nev.	Date	Page	Summary
0.01	Oct 30, 2009	_	First Edition issued
1.00	Nov 02, 2010	All pages	"Preliminary", "Under development" deleted
		4	Table 1.3 revised
		28 to 54	"5. Electrical Characteristics" added
1.10	Nov 02, 2010	_	TN-R8C-A015A/E reflected
		3	Table 1.2 "Timer RG" and "Package" revised
		4 and 5	Tables 1.3 and 1.4 revised
		6	Figure 1.1 revised
		8	Figure 1.3 "PTQP0064LB-A" added
		17	Figure 3.1 "Part Number" revised
		33	Table 5.3 "tCONV", "tSAMP" revised
		47	Table 5.21 revised
		51	Table 5.28 revised
		55	Table 5.35 revised
		59	Package (PTQP0064LB-A) added

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